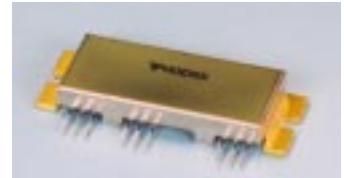


PA1166 **1930-1990 MHz.**
6 Watt **28v. GaAs Ultra Linear Power**
Amplifier **Amplifier**



M/A-COM



Features (typical values)

- High IP3** +53.0 dBm.
- Low NF** 3.0 dB.
- High Output Power** +37.5 dBm.
- Low Cost**

Parameter	Typical Value	Min. Value	Max. Value	Units
Frequency		1930	1990	MHz.
Gain	26.0	23.0		dB.
Gain Flatness	+/- 0.3			dB.
Pout @ 1dB. comp.	38	37		dBm.
Noise Figure	2.7		4.0	dB.
ACPR (30kHz. BW)*	-54.0			dBc.
VSWR (Input/Output)	1.5:1/2:1		2:1/3:1	
IP3 (two tone)**	+53.0	+48.0		dBm.
Supply Required***	+28/1000		+28/1200	v./mA.

* ± 850kHz from fc at power level of 30dBm. (IS-95)

** IP3 measured with 2 tones @+24dBm. per tone @ 1MHz apart

*** A 10 micro farad capacitor is required from pin3 (+V) to ground
 Min and max values from 0 to 85 degrees C

Outline Drawings

See Attached Document

Maximum Ratings

- Storage Temperature -40°C to +125°C
- DC Voltage +30 volts
- RF Input Power +15 dBm.
- Case Temperature +90°C

Typical Performance @+ 25°C

